



DMN12M7UCA10

N-CHANNEL ENHANCEMENT MODE MOSFET

Product Summary

| BV _{SSS} | R _{SS(ON)} Typ | Is мах Та = +25°С |
|-------------------|---|----------------------|
| 12V | $2.3 \text{ m}\Omega @ V_{GS} = 3.8 \text{V}$ | 20.2A |

Description

This new generation MOSFET is designed to minimize the on-state resistance (Rss(ON)) and yet maintain superior switching performance, making it ideal for high efficiency power management applications.

Applications

- Battery Management
- Load Switch
- Battery Protection

Features

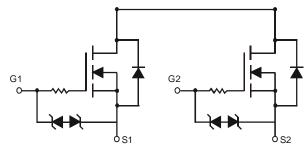
- CSP with Footprint 2.98mm × 1.49mm
- Height = 0.11mm for Low Profile
- ESD Protection of Gate
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- For automotive applications requiring specific change control (i.e. parts qualified to AEC-Q100/101/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please <u>contact us</u> or your local Diodes representative. <u>https://www.diodes.com/quality/product-definitions/</u>

Mechanical Data

- Case: X4-DSN3015-10
- Terminal Connections: See Diagram Below
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish NiPdAu or NiAu. Solderable per MIL-STD-202, Method 208 @4
- Weight: 0.0012 grams (Approximate)



Source 1: 1,2,4,5 Top View Gate 1: 3 Source 2: 6, 7, 9, 10 Gate 2: 8



Equivalent Circuit

Ordering Information (Note 4)

| | | . |
|----------------|---------------|------------------|
| Part Number | Case | Packaging |
| DMN12M7UCA10-7 | X4-DSN3015-10 | 5000/Tape & Reel |

No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

4

Marking Information

| | MF | |
|---|----|--|
| • | ΥM | |

 $\begin{array}{l} \mathsf{MF} = \mathsf{Product Type Marking Code} \\ \mathsf{YM} = \mathsf{Date Code Marking} \\ \mathsf{Y or } \overline{\mathsf{Y}} = \mathsf{Year} \ (\mathsf{ex: G} = 2019) \\ \mathsf{M or } \overline{\mathsf{M}} = \mathsf{Month} \ (\mathsf{ex: 9} = \mathsf{September}) \end{array}$

Date Code Key

Notes:

| Year | 2018 | 2019 | 2020 | 2021 | 2022 | 2023 | 2024 | 2025 | 2026 | 2027 | 2028 | 2029 |
|-------|------|------|------|------|------|------|------|------|------|------|------|------|
| Code | F | G | Н | I | J | К | L | М | Ν | 0 | Р | R |
| | | 1 | | | | | | | | | | |
| Month | Jan | Feb | Mar | Apr | Мау | Jun | Jul | Aug | Sep | Oct | Nov | Dec |

X4-DSN3015-10



Maximum Ratings (@TA = +25°C, unless otherwise specified.)

| Characteristic | Symbol | Value | Unit | | | |
|---|--------|------------------------|------|------|---|--|
| Source-Source Voltage | Vsss | 12 | V | | | |
| Gate-Source Voltage | | | Vgss | ±8 | V | |
| | Steady | T _A = +25°C | | 20.2 | А | |
| Continuous Source Current (Note 5) V _{GS} = 4.5V | State | $T_A = +70^{\circ}C$ | Is | 16.1 | | |
| | | 13.6 | • | | | |
| Continuous Source Current (Note 5) VGS = 2.5V | Is | 10.8 | A | | | |
| Pulsed Source Current (Note 6) | Ism | 80 | А | | | |

Thermal Characteristics

| Characteristic | Symbol | Value | Unit |
|--|------------------|-------------|------|
| Power Dissipation (Note 7) | PD | 0.74 | W |
| Thermal Resistance, Junction to Ambient $@T_A = +25^{\circ}C$ (Note 7) | R _{0JA} | 171.9 | °C/W |
| Power Dissipation (Note 5) | PD | 1.73 | W |
| Thermal Resistance, Junction to Ambient $@T_A = +25^{\circ}C$ (Note 5) | Reja | 74.4 | °C/W |
| Operating and Storage Temperature Range | TJ, TSTG | -55 to +150 | °C |

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

| Characteristic | Symbol | Min | Тур | Max | Unit | Test Condition | | |
|--|---------------------|------|------|------|------|---|--|--|
| OFF CHARACTERISTICS (Note 8) | | | | | | | | |
| Source-Source Breakdown Voltage | BV _{SSS} | 12 | — | | V | $V_{GS} = 0V, I_S = 1mA$ | | |
| Zero Gate Voltage Drain Current TJ = +25°C | Isss | _ | — | 1 | μA | $V_{SS} = 9.6V, V_{GS} = 0V$ | | |
| Gate-Source Leakage | | — | — | ±10 | μA | $V_{GS} = \pm 8V, V_{SS} = 0V$ | | |
| Gale-Source Leakage | IGSS | _ | — | ±1 | μA | $V_{GS} = \pm 5V, V_{SS} = 0V$ | | |
| ON CHARACTERISTICS (Note 8) | | | | | | | | |
| Gate Threshold Voltage | V _{GS(TH)} | 0.5 | 0.8 | 1.4 | V | Vss = 10V, Is = 1.11mA | | |
| | | 1.55 | 2.19 | 2.75 | | V _{GS} = 4.5V, I _S = 6A | | |
| Static Source-Source On-Resistance | D | 1.6 | 2.30 | 2.85 | mΩ | V _{GS} = 3.8V, I _S = 6A | | |
| Static Source-Source On-Resistance | R _{SS(ON)} | 1.65 | 2.51 | 3.95 | | V _{GS} = 3.1V, I _S = 6A | | |
| | | 1.9 | 2.93 | 6.1 | | V _{GS} = 2.5V, I _S = 6A | | |
| Diode Forward Voltage | V _{SS} | _ | 0.8 | 1.2 | V | $V_{GS} = 0V, I_S = 6A$ | | |
| DYNAMIC CHARACTERISTICS (Note 9) | | | | | | | | |
| Input Capacitance | Ciss | _ | 3039 | _ | | | | |
| Output Capacitance | Coss | _ | 530 | _ | pF | Vss = 10V, Vgs = 0V, f = 1MHz | | |
| Reverse Transfer Capacitance | Crss | _ | 141 | _ | | I = I I V I I Z | | |
| Total Gate Charge | Qg | _ | 35.7 | — | | | | |
| Gate-Source Charge | Qgs | _ | 6.7 | _ | nC | $V_{SS} = 6V, V_{GS} = 4V,$ | | |
| Gate-Drain Charge | Q _{gd} | _ | 9.2 | — | | $I_{S} = 6A$ | | |
| Gate Charge at V⊤н | Qg(th) | - | 3.4 | _ | | | | |
| Turn-On Delay Time | tD(ON) | | 880 | | | | | |
| Turn-On Rise Time | t _R | | 1468 | | | $V_{SS} = 6V, V_{GS} = 4V,$ | | |
| Turn-Off Delay Time | tD(OFF) | | 2914 | | ns | Is = 6A | | |
| Turn-Off Fall Time | tF | | 2830 | | | | | |

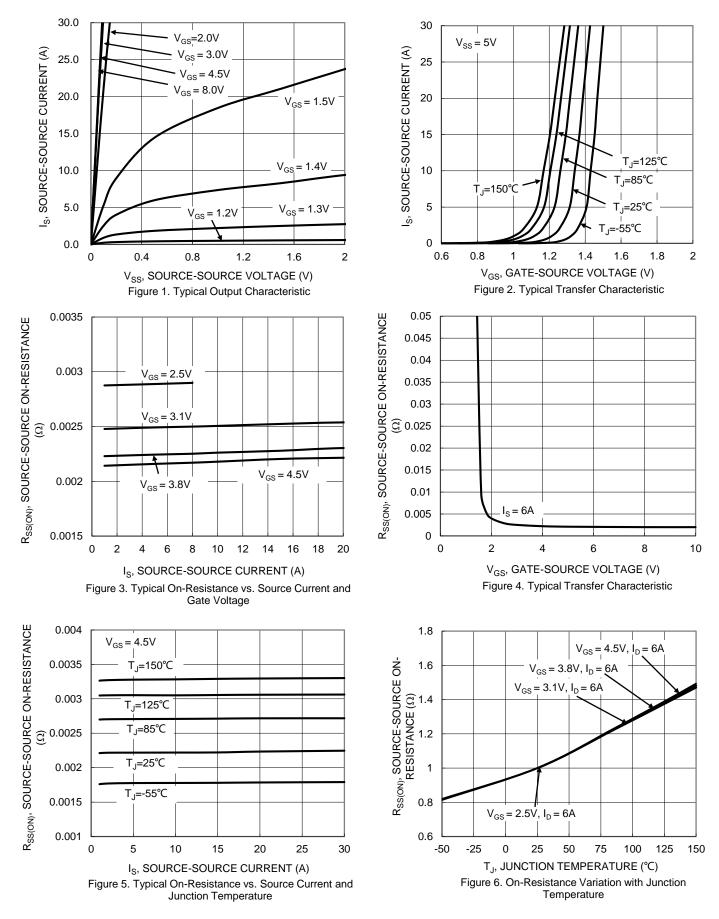
 Device mounted on FR-4 material with 1inch² (6.45cm²), 2oz. (0.071mm thick) Cu.
Repetitive rating, pulse width limited by junction temperature.
Device mounted on FR-4 PCB with minimum recommended pad layout, single sided. Notes:

8. Short duration pulse test used to minimize self-heating effect.

9. Guaranteed by design. Not subject to production testing.

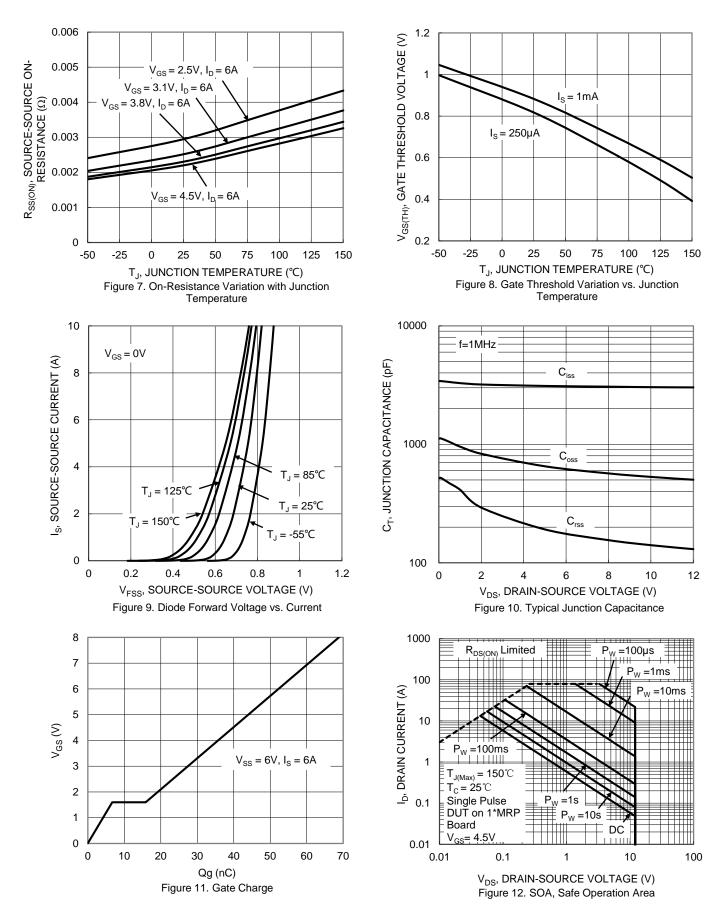


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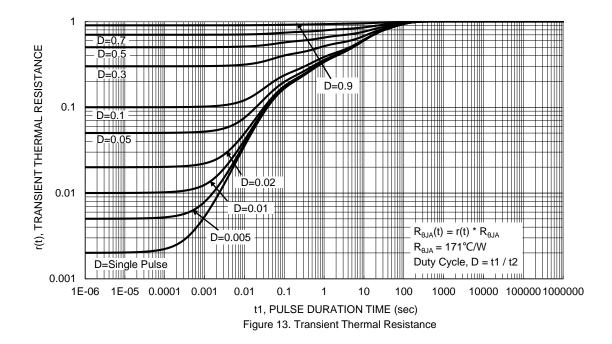
DMN12M7UCA10 Document number: DS40841 Rev. 3 - 2









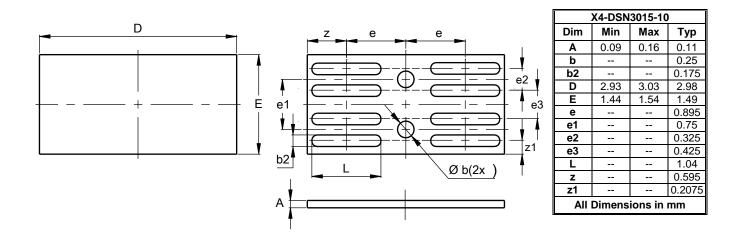




Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

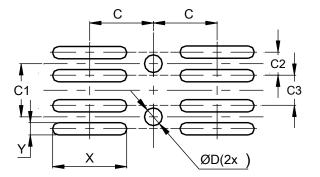
X4-DSN3015-10



Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

X4-DSN3015-10



| Dimensions | Value (in mm) | | | |
|------------|------------------|--|--|--|
| С | 0.895 | | | |
| C1 | 0.750 | | | |
| C2 | 0.325 | | | |
| C3 | 0.425 | | | |
| D | 0.25 | | | |
| Х | 1.04 | | | |
| Y | 0.175 | | | |



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